FAIRCHILD

SEMICONDUCTOR®

FDB8160_F085 N-Channel PowerTrench[®] MOSFET

30V, 80A, 1.8m Ω

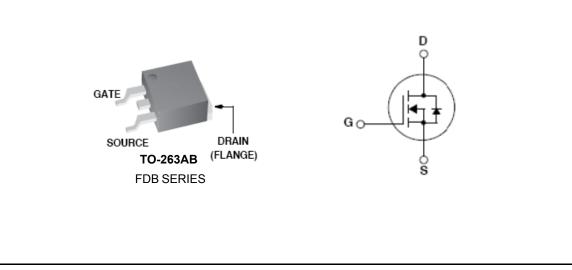
Features

- Typ $r_{DS(on)}$ = 1.5m Ω at V_{GS} = 10V, I_D = 80A
- Typ Q_{g(10)} = 187nC at V_{GS} = 10V
- Low Miller Charge
- Low Qrr Body Diode
- UIS Capability (Single Pulse and Repetitive Pulse)
- Qualified to AEC Q101
- RoHS Compliant

Applications

- 12V Automotive Load Control
- Starter/Alternator Systems
- Electronic Power Steering Systems
- DC/DC converter





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October 2010

MOSFET Maximum Ratings $T_C = 25^{\circ}C$ unless otherwise noted

Symbol	Parameter		Ratings	Units	
V _{DSS}	Drain to Source Voltage		30	V	
V _{GS}	Gate to Source Voltage		±20	V	
1	Drain Current Continuous (T _C < 160°C, V _{GS} = 10V)		80	А	
D	Pulsed		See Figure 4	A	
E _{AS}	Single Pulse Avalanche Energy	(Note 1)	1290	mJ	
Р	Power Dissipation		254	W	
P _D	Derate above 25°C		1.7	W/ºC	
T _J , T _{STG}	Operating and Storage Temperature		-55 to +175	°C	

Thermal Characteristics

R_{\thetaJC}	Maximum Thermal Resistance Junction to Case	0.59	°C/W
R_{\thetaJA}	Maximum Thermal Resistance Junction to Ambient TO-263,1in ² copper pad area	43	°C/W

Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FDB8160	FDB8160_F085	TO-263AB	330mm	24mm	800 units

Electrical Characteristics T_J = 25°C unless otherwise noted

Symbol	Parameter	Test Conditions		Тур	Мах	Units
Off Cha	racteristics					
B _{VDSS}	Drain to Source Breakdown Voltage	$I_{D} = 250 \mu A, V_{GS} = 0 V$	30	-	-	V
	Zero Gate Voltage Drain Current	V _{DS} = 24V, V _{GS} = 0V	-	-	1	۸
DSS		T _J = 150°C	-	-	250	μA
GSS	Gate to Source Leakage Current	$V_{GS} = \pm 20V$	-	-	±100	nA

On Characteristics

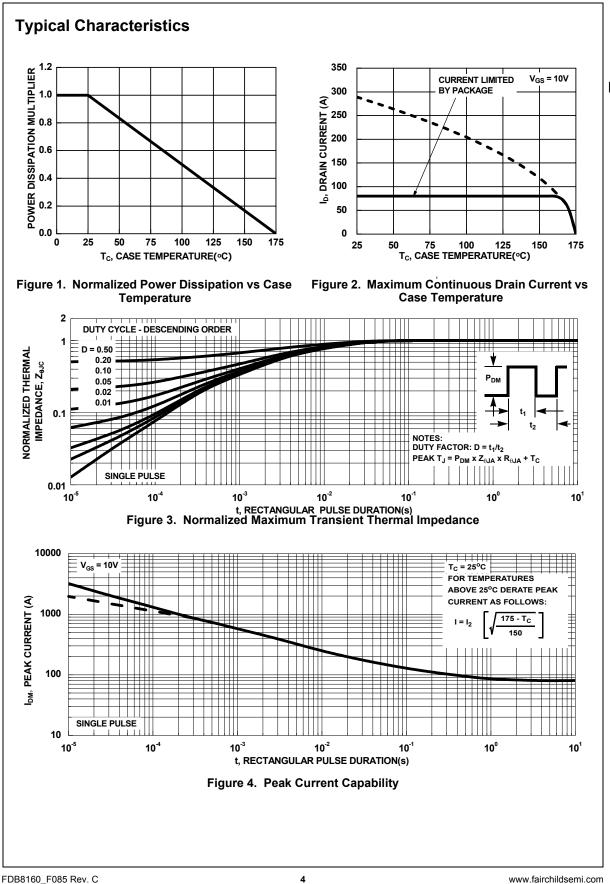
V _{GS(th)}	Gate to Source Threshold Voltage	$V_{GS} = V_{DS}, I_D = 250 \mu A$	2	2.9	4	V
r	Drain to Source On Resistance	I _D = 80A, V _{GS} = 10V	-	1.5	1.8	mΩ
r _{DS(on)}	Drain to Source On Resistance	I_D = 80A, V_{GS} = 10V, T_J = 175°C	-	2.6	3.1	mΩ

Dynamic Characteristics

C _{iss}	Input Capacitance		0)/	-	11825	-	pF
C _{oss}	Output Capacitance		V _{DS} = 15V, V _{GS} = 0V, f = 1MHz		1810	-	pF
C _{rss}	Reverse Transfer Capacitance				1240	-	pF
Rg	Gate Resistance	f = 1MHz		-	1.75	-	Ω
Q _{g(TOT)}	Total Gate Charge at 10V	V _{GS} = 0 to 10V		-	187	243	nC
Q _{g(th)}	Threshold Gate Charge	V_{GS} = 0 to 2V	V _{DD} = 15V	-	20	26	nC
Q _{gs}	Gate to Source Gate Charge		I _D = 80A	-	43	-	nC
Q _{gs2}	Gate Charge Threshold to Plateau			-	23	-	nC
Q _{gd}	Gate to Drain "Miller" Charge			-	57	-	nC

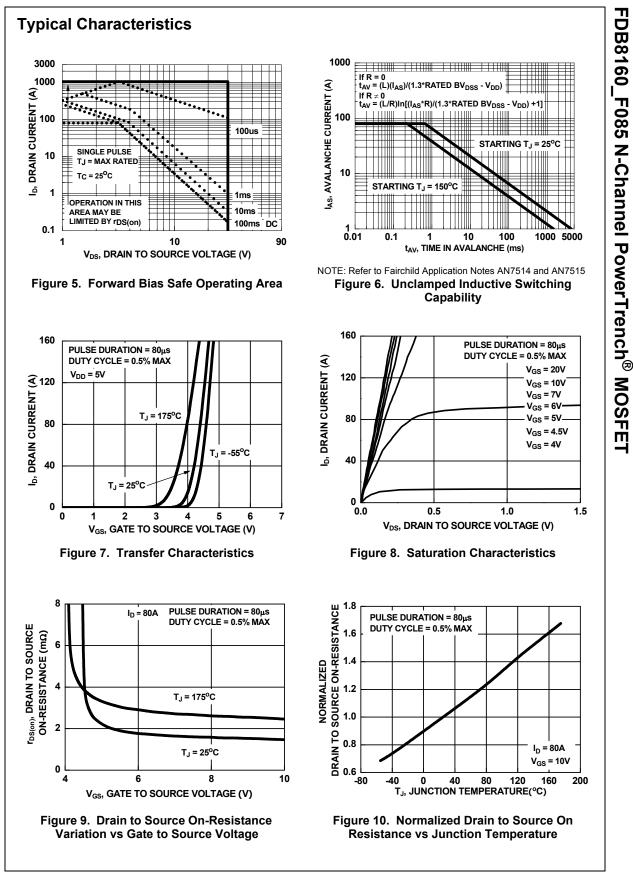
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ymbol	Parameter	Test Conditions	Min	Тур	Max	Units
witch	ing Characteristics					
1	Turn-On Time		-	-	60	ns
on)	Turn-On Delay Time		-	17.2	-	ns
,	Turn-On Rise Time	V _{DD} = 15V, I _D = 80A,	-	18.9	-	ns
off)	Turn-Off Delay Time	$V_{GS} = 10V, R_{GS} = 1.3\Omega$	-	60	-	ns
	Turn-Off Fall Time		-	27	-	ns
:	Turn-Off Time		-	-	137	ns
ain-S	ource Diode Characteristics					
	Source to Drain Diode Voltage	I _{SD} = 80A	-	0.9	1.25	V
D	Source to Drain Diode Voltage	I _{SD} = 40A	-	0.8	1.0	V
-	Reverse Recovery Time	I _F = 80A, dI _{SD} /dt = 100A/μs	-	48	62	ns
	Reverse Recovery Charge	$I_F = 80A$, $dI_{SD}/dt = 100A/\mu s$	-	42	55	nC

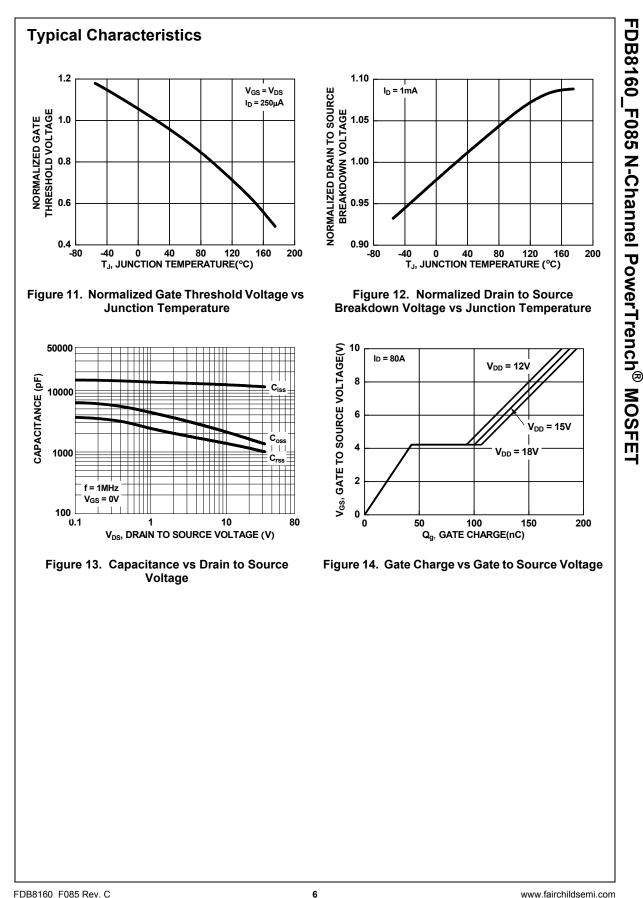


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